COMPLIANT

HALOGEN FREE

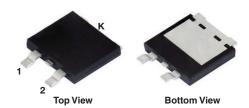


# Vishay General Semiconductor

# Dual High-Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.36 \text{ V}$  at  $I_F = 5 \text{ A}$ 

# eSMP<sup>®</sup> Series SMPD (TO-263AC)





## **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 30 A			
$V_{RRM}$	100 V			
I <sub>FSM</sub>	320 A			
$V_F$ at $I_F = 30 \text{ A} (T_A = 125 ^{\circ}\text{C})$	0.66 V			
T <sub>J</sub> max.	150 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

## **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60D100C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	100	V	
Maximum average forward rectified current (fig. 1)	per device		60	Δ.	
	per diode	I <sub>F(AV)</sub>	30	A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	320	А	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.45	-	V	
	I <sub>F</sub> = 15 A			0.62	-		
	I <sub>F</sub> = 30 A			0.75	0.81		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.36	-		
	I <sub>F</sub> = 15 A			0.54	-		
	I <sub>F</sub> = 30 A			0.66	0.73		
Reverse current at rated V <sub>R</sub> per diode	V <sub>R</sub> = 70 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> (2)	12	-	μΑ	
		T <sub>A</sub> = 125 °C		11	-	mA	
	V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C		-	1000	μΑ	
	v <sub>R</sub> = 100 v	T <sub>A</sub> = 125 °C		27	85	mA	

#### **Notes**

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60D100C	UNIT	
Typical thermal resistance	per diode	R <sub>0</sub> JC (3)	1.8		
	per device	R <sub>0</sub> JC (3)	0.95	°C/W	
	per device	R <sub>0JM</sub> (2)	3		
	per device	$R_{\theta JA}^{(1)(2)}$	45		

#### Notes

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$
- (2) Free air mounted on recommended pad size 2 OZ. FR4 PCB; thermal resistance R<sub>eJA</sub> junction to ambient; thermal resistance R<sub>eJM</sub> junction
- $^{(3)}$  Thermal resistance  $R_{\theta JC}$  junction to K (heatsink). Mounted on infinite heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SMPD (TO-263AC)	V60D100C-M3/I	0.55	1	2000/reel	13" diameter plastic tape and reel
SMPD (TO-263AC)	V60D100CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel

## Note

(1) AEC-Q101 qualified



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## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

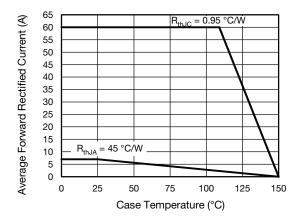


Fig. 1 - Forward Current Derating Curve

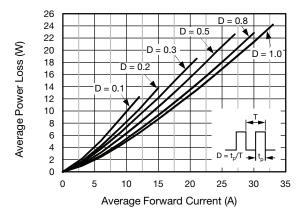


Fig. 2 - Forward Power Loss Characteristics Per Diode

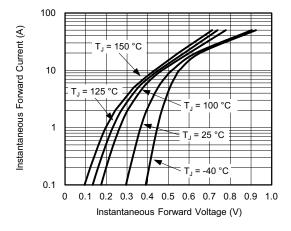


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

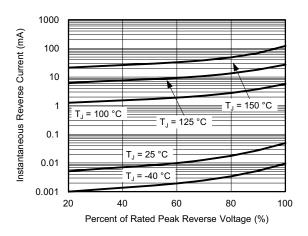


Fig. 4 - Typical Reverse Characteristics Per Diode

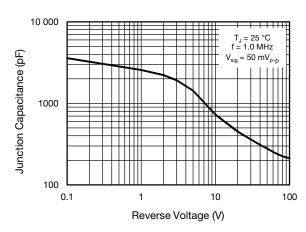


Fig. 5 - Typical Junction Capacitance Per Diode

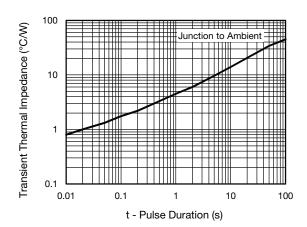


Fig. 6 - Typical Transient Thermal Impedance Per Device





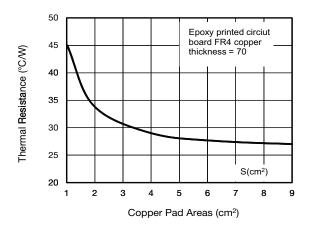
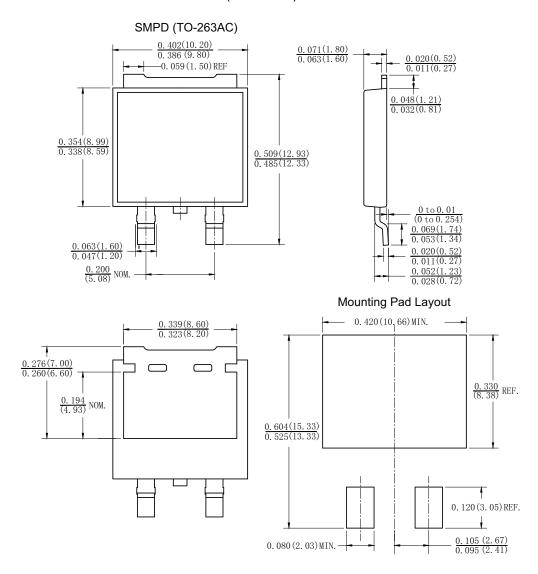


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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